

Description

The AU2422PUW is a bi-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The AU2422PUW complies with the IEC 61000-4-2 (ESD) with ±30kV air and ±30kV contact discharge. The small size and high ESD surge protection make AU2422PUW an ideal choice to protect cell phone, digital cameras, audio players and many other portable applications.

Features

- Ultra low leakage: nA level
- Operating voltage: 24V
- Low clamping voltage
- Protects two bi-directional lines
- Complies with following standards:
 IEC 61000-4-2 (ESD) immunity test Air discharge: ±30kV
 - Contact discharge: ±30kV
 - IEC61000-4-5 (Lightning) 5A (8/20µs)
- RoHS Compliant

Mechanical Characteristics

- Package: DFN1110-3A
- Case Material: "Green" Molding Compound.
- Terminal Connections: See Diagram Below
- Marking Information: See Below

Applications

- HDMI 1.3/1.4/2.0, USB 2.0/3.0 and MDDI ports
- Monitors and flat panel displays
- Set-top box and Digital TV
- Video graphics cards
- Digital Visual Interface (DVI)
- Notebook Computers
- PCI Express and Serial SATA Ports

Marking Information

42U

42U = Device Marking Code

Equivalent Circuit and Pin Configuration



Ordering Information

Part Number	Packaging	Reel Size	
AU2422PUW	10000/Tape & Reel	7 inch	

Circuit and Pin Schematic



Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20µs)	Ppk	170	W
Peak Pulse Current (8/20µs)	IPP	5	А
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	Vesd	±30 ±30	kV
Operating Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	Tstg	−55 to +150	°C

Electrical Characteristics (T_A=25°C unless otherwise specified)

Parameter	Symbol	Min	Тур	Мах	Unit	Test Condition
Reverse Working Voltage	VRWM			24	V	
Breakdown Voltage	Vbr	26.5			V	IT = 1mA
Reverse Leakage Current	I _R			0.2	μA	VRWM = 24V
Clamping Voltage	Vc			34	V	IPP = 5A (8 x 20µs pulse)
COD Clamping Voltage ⁽¹⁾	Vc		27.2		V	IPP = 4A, tp = 0.2/100ns (TLP)
ESD Clamping Voltage			34		V	IPP = 16A, tp = 0.2/100ns (TLP)
Dynamic Resistance ⁽²⁾	R _{DYN}		0.57		Ohm	tp = 0.2/100ns (TLP)
Junction Capacitance	Сл		5		pF	VR = 0V, f = 1MHz

(1) Transmission Line Pulse Test (TLP) Settings: tp = 100ns, tr = 0.2ns.

(2) Dynamic resistance calculated from ITLP = 4A to ITLP = 16A.



Typical Performance Characteristics (TA=25°C unless otherwise Specified)

Junction Capacitance vs. Reverse Voltage



Clamping Voltage vs. Peak Pulse Current (tp = 8/20µs)



8 X 20µs Pulse Waveform



Peak Pulse Power vs. Pulse Time



TLP Measurement



ESD Clamping Voltage 8 kV Contact per IEC61000-4-2



DFN1110-3A Package Outline Drawing





Symbol	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A	0.400	0.500	0.016	0.020	
A1	0.000	0.050	0.000	0.002	
A2	0.100MIN.		0.004MIN.		
A3	0.127	MIN.	0.005MIN.		
D	1.050	1.150	0.041	0.045	
E	0.950	1.050	0.037	0.041	
D1	0.750	0.850	0.030	0.033	
E1	0.350	0.450	0.014	0.018	
b	0.200	0.300	0.008	0.012	
b1	0.200	0.300	0.008	0.012	
b2	b2 0.200MIN.		0.008MIN.		
е	0.600	0.700	0.024	0.028	
L	0.140	0.240	0.006	0.009	
L1	0.100REF.		0.004REF.		
L2	0.210	0.310	0.008	0.012	
L3	0.000	0.070	0.000	0.003	

Contact Information

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